

TEMIC

Siliconix

P-Channel JFETs

J/SST270 Series

J270	SST270
J271	SST271

Product Summary

Part Number	V _{GS(off)} (V)	V _{(BR)GSS} Min (V)	g _{fs} Min (mS)	I _{DSS} Min (mA)
J/SST270	0.5 to 2.0	30	6	-2
J/SST271	1.5 to 4.5	30	8	-6

Features

- Low Cutoff Voltage: J270 <2 V
- High Input Impedance
- Very Low Noise
- High Gain

Benefits

- Full Performance from Low-Voltage Power Supply: Down to 2 V
- Low Signal Loss/System Error
- High System Sensitivity
- High-Quality, Low-Level Signal Amplification

Applications

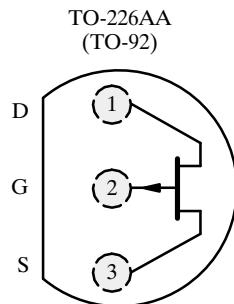
- High-Gain, Low-Noise Amplifiers
- Low-Current, Low-Voltage Battery Amplifiers
- Ultrahigh Input Impedance Pre-Amplifiers
- High-Side Switching

Description

The J/SST270 series consists of all-purpose amplifiers for designs requiring p-channel operation.

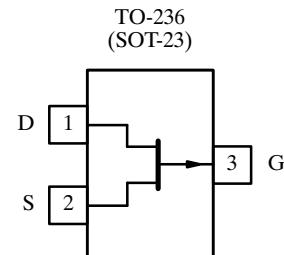
The TO-226AA (TO-92) plastic package provides a

low-cost option, while the TO-236 (SOT-23) package provides surface-mount capability. Both the J and SST series are available in tape-and-reel for automated assembly (see Packaging Information).



Top View

J270
J271



Top View

SST270 (S0)*
SST271 (S1)*

*Marking Code for TO-236

Absolute Maximum Ratings

Gate-Drain Voltage	30 V
Gate-Source Voltage	30 V
Gate Current	-50 mA
Storage Temperature	-55 to 150°C
Operating Junction Temperature	-55 to 150°C

Lead Temperature (1/16" from case for 10 sec.) 300°C

Power Dissipation^a 350 mW

Notes

a. Derate 2.8 mW/°C above 25°C

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Specifications^a

Parameter	Symbol	Test Conditions	Typ ^b	Limits				Unit	
				J/SST270		J/SST271			
				Min	Max	Min	Max		
Static									
Gate-Source Breakdown Voltage	V _{(BR)GSS}	I _G = 1 μA, V _{DS} = 0 V	45	30		30		V	
Gate-Source Cutoff Voltage	V _{GS(off)}	V _{DS} = -15 V, I _D = -1 nA		0.5	2.0	1.5	4.5		
Saturation Drain Current ^c	I _{DSS}	V _{DS} = -15 V, V _{GS} = 0 V		-2	-15	-6	-50	mA	
Gate Reverse Current	I _{GSS}	V _{GS} = 20 V, V _{DS} = 0 V	10		200		200	pA	
		T _A = 125°C	5					nA	
Gate Operating Current	I _G	V _{DG} = -15 V, I _D = -1 mA	10					pA	
Drain Cutoff Current	I _{D(off)}	V _{DS} = -15 V, V _{GS} = 10 V	-10						
Gate-Source Forward Voltage	V _{GS(F)}	I _G = -1 mA, V _{DS} = 0 V	-0.7					V	
Dynamic									
Common-Source Forward Transconductance	g _{fs}	V _{DS} = -15 V, V _{GS} = 0 V f = 1 kHz		6	15	8	18	mS	
Common-Source Output Conductance	g _{os}				200		500	μS	
Common-Source Input Capacitance	C _{iss}	V _{DS} = -15 V, V _{GS} = 0 V f = 1 MHz	20						
Common-Source Reverse Transfer Capacitance	C _{rss}		4					pF	
Equivalent Input Noise Voltage	ē _n	V _{DG} = -10 V, V _{GS} = 0 V f = 1 kHz	20					nV/ √Hz	

Notes

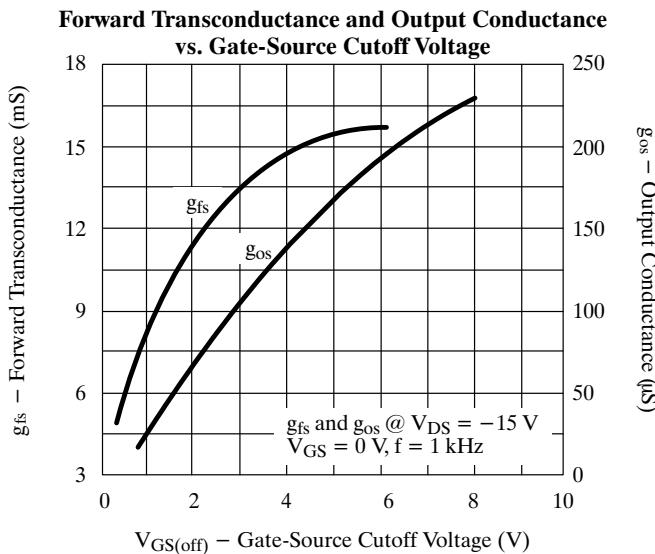
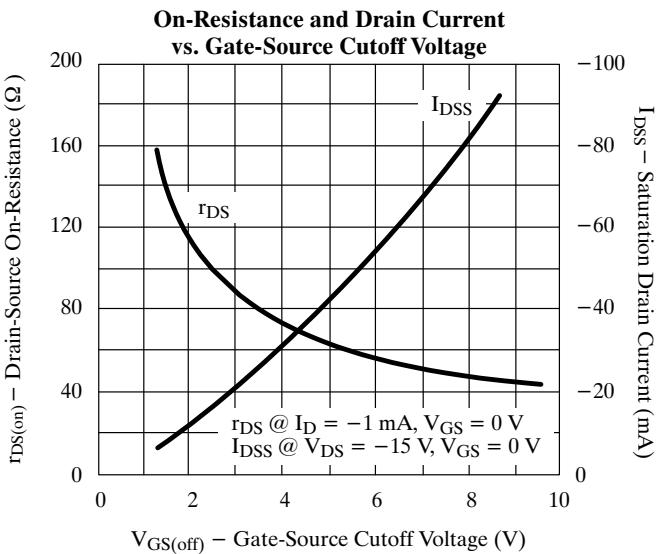
a. T_A = 25°C unless otherwise noted.

PSCIA

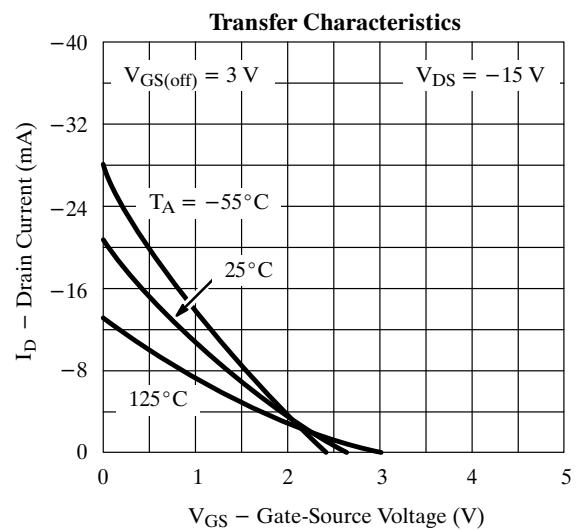
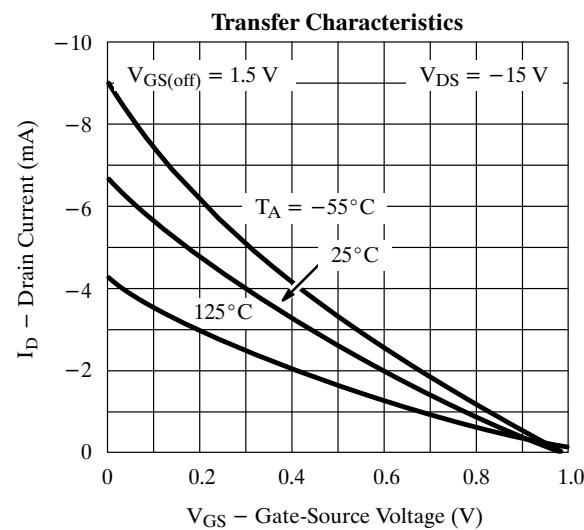
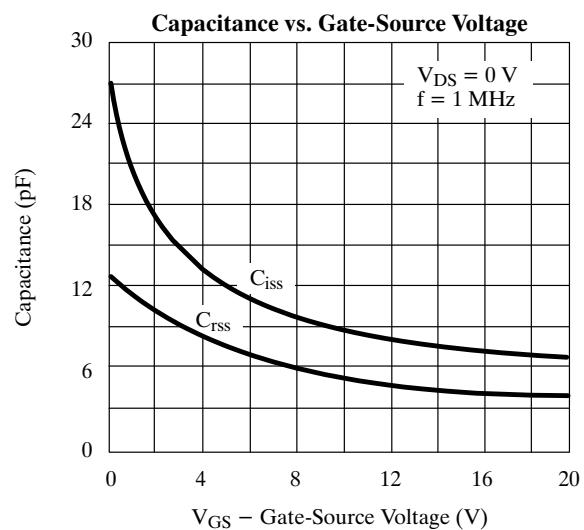
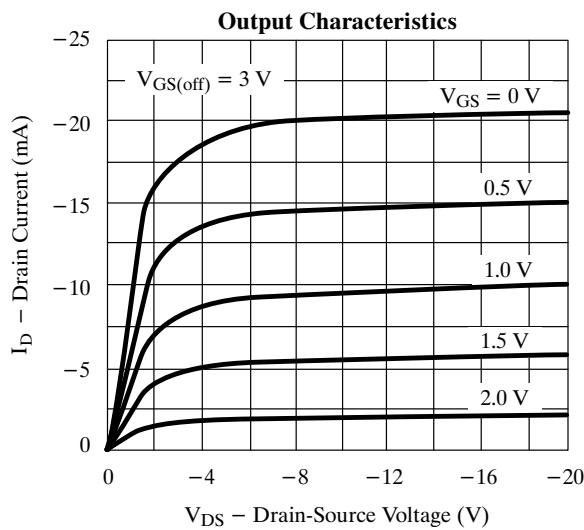
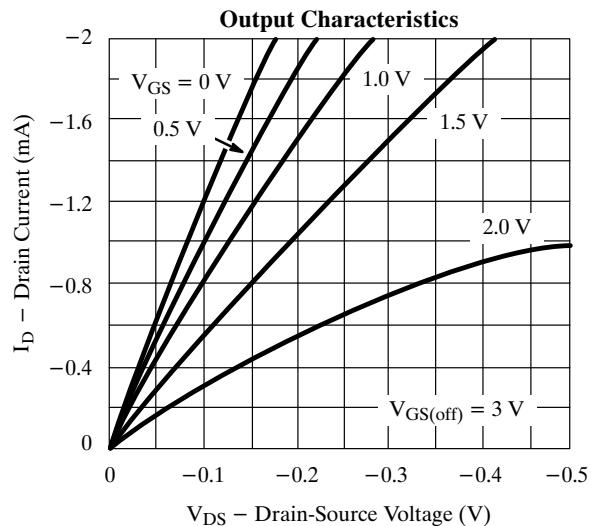
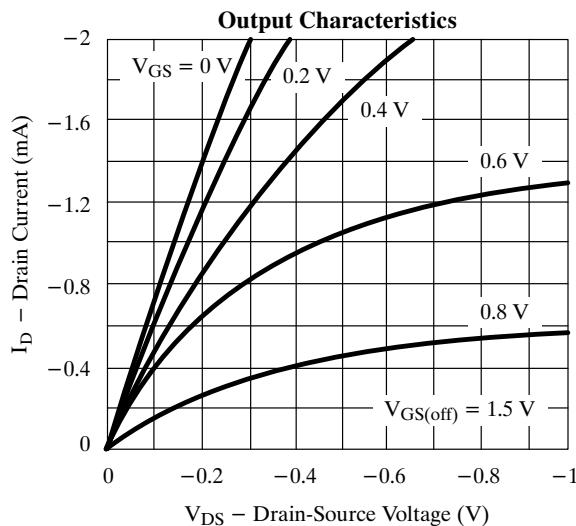
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

c. Pulse test: PW ≤ 300 μs duty cycle ≤ 3%.

Typical Characteristics



Typical Characteristics (Cont'd)



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Typical Characteristics (Cont'd)

